

Flexible and Transparent Artificial Synapse Devices Based on Thin-Film Transistors with Nanometer Thickness [Corrigendum]

Dai C, Huo C, Qi S, Dai M, Webster T, Xiao H.
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The authors apologize for this error and advise it does not affect the results of the paper.

The authors have advised that due to a mismatch between the device and the SEM image, Figure 1C on page 8038 is incorrect. The correct Figure 1 is shown below.

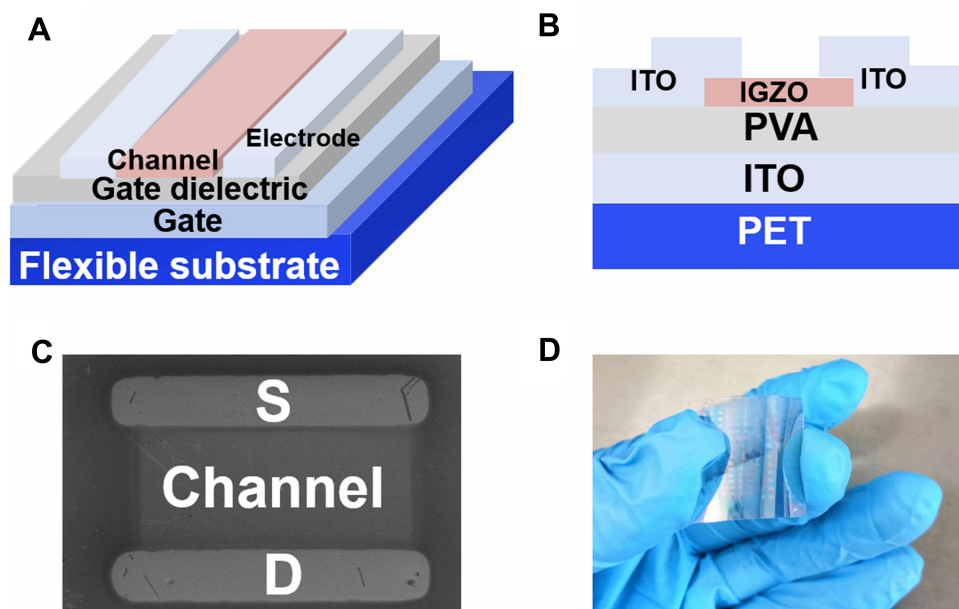


Figure 1 Thin-film transistor-based synapse device. (A) Three-dimensional structure of the single thin film transistor. (B) Cross-section structure of the single thin film transistor. (C) SEM top image of a single device and (D) Flexible transparent single device in an enlarged image.

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